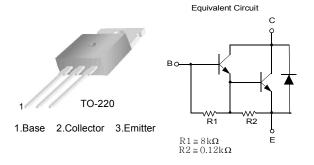


October 2008

# **TIP120/TIP121/TIP122 NPN Epitaxial Darlington Transistor**

- · Medium Power Linear Switching Applications
- Complementary to TIP125/126/127



## Absolute Maximum Ratings\* $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{CBO}$	Collector-Base Voltage : TIP120	60	V
	: TIP121	80	V
	: TIP122	100	V
$V_{CEO}$	Collector-Emitter Voltage: TIP120	60	V
	: TIP121	80	V
	: TIP122	100	V
$V_{EBO}$	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current (DC)	5	Α
I <sub>CP</sub>	Collector Current (Pulse)	8	Α
I <sub>B</sub>	Base Current (DC)	120	mA
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	2	W
	Collector Dissipation (T <sub>C</sub> =25°C)	65	W
$T_J$	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

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<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### **Electrical Characteristics\*** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	Collector-Emitter Sustaining Voltage : TIP120 : TIP121 : TIP122	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0	60 80 100			V V
I <sub>CEO</sub>	Collector Cut-off Current : TIP120 : TIP121 : TIP122	$V_{CE} = 30V, I_B = 0$ $V_{CE} = 40V, I_B = 0$ $V_{CE} = 50V, I_B = 0$			0.5 0.5 0.5	mA mA mA
Ісво	Collector Cut-off Current : TIP120 : TIP121 : TIP122	$V_{CB} = 60V, I_{E} = 0$ $V_{CB} = 80V, I_{E} = 0$ $V_{CB} = 100V, I_{E} = 0$			0.2 0.2 0.2	mA mA mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$			2	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = 3V, I_{C} = 0.5A$ $V_{CE} = 3V, I_{C} = 3A$	1000 1000			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	$I_C = 3A, I_B = 12mA$ $I_C = 5A, I_B = 20mA$			2.0 4.0	V V
V <sub>BE</sub> (on)	* Base-Emitter On Voltage	$V_{CE} = 3V, I_{C} = 3A$			2.5	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 0.1MHz			200	pF

<sup>\*</sup> Pulse Test: Pulse Width≤300µs, Duty Cycle≤2%

## **Typical characteristics**

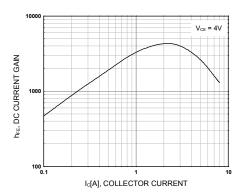


Figure 1. DC current Gain

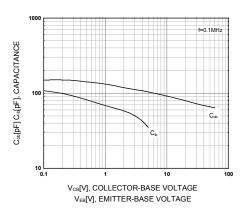


Figure 3. Output and Input Capacitance vs. Reverse Voltage

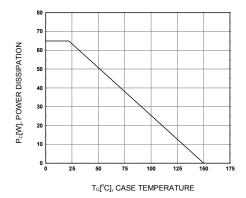


Figure 5. Power Derating

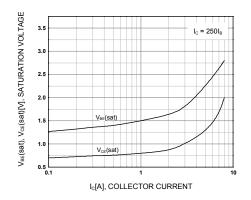


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

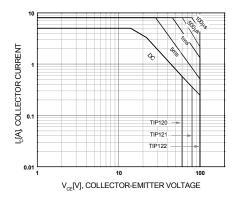
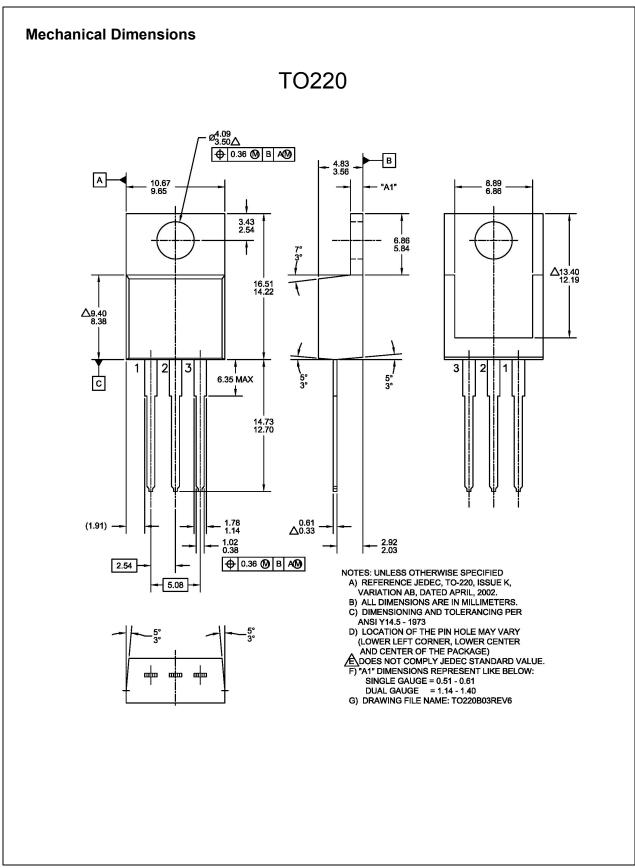


Figure 4. Safe Operating Area







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